imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

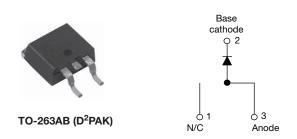


www.vishay.com

VS-MBRB1035PbF, VS-MBRB1045PbF

Vishay Semiconductors

High Performance Schottky Rectifier, 10 A



PRODUCT SUMMARY							
Package	TO-263AB (D ² PAK)						
I _{F(AV)}	10 A						
V _R	35 V, 45 V						
V_F at I_F	0.57 V						
I _{RM} max.	15 mA at 125 °C						
T _J max.	150 °C						
Diode variation	Single die						
E _{AS}	8.0 mJ						

FEATURES

- 150 °C T_J operation
- TO-220 and D²PAK packages
- · Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
 RoHS compliant HALOGEN
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201, class 1A whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	MBOL CHARACTERISTICS VALUES								
I _{F(AV)}	Rectangular waveform	10	٨						
I _{FRM}	T _C = 135 °C	20	A						
V _{RRM}		35, 45	V						
I _{FSM}	t _p = 5 μs sine	1060	A						
V _F	10 A _{pk} , T _J = 125 °C	0.57	V						
TJ	Range	-65 to +150	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-MBRB1035PbF	VS-MBRB1045PbF	UNITS					
Maximum DC reverse voltage	V _R	35	45	V					
Maximum working peak reverse voltage	V _{RWM}		45	v					

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CON	IDITIONS	VALUES	UNITS				
Maximum average forward current	I _{F(AV)}	$T_{C} = 135 \text{ °C}, \text{ rated } V_{R}$		10					
Peak repetitive forward current	I _{FRM}	Rated V _R , square wave, 20 kHz, T	_C = 135 °C	20					
Non-repetitive surge current	I _{FSM}	5 μs sine	Following any rated load condition and with rated V _{RRM} applied	1060	А				
		Surge applied at rated load conditi	150						
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 2 \text{ A}, L = 4 \text{ mH}$	8	mJ					
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero ir Frequency limited by T _J maximum	2	А					

Revision: 17-Nov-16

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

1



Vishay Semiconductors

ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS						
		20 A	T _J = 25 °C	0.84	V				
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	T _{.1} = 125 °C	0.57					
		20 A	1j = 125 C	0.72					
Maximum instantaneous reverse	I(1)	$T_J = 25 \ ^\circ C$	Rated DC voltage	0.1	mA				
current	I _{RM} (1)	T _J = 125 °C	haled DC vollage	15					
Threshold voltage	V _{F(TO)}			0.354	V				
Forward slope resistance	r _t	ij = ij maximum	$T_J = T_J maximum$		mΩ				
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal rang	600	pF					
Typical series inductance	Ls	Measured from top of term	8.0	nH					
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs					

Note

 $^{(1)}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction tempera	ture range	TJ		-65 to +150	°C			
Maximum storage temperat	ure range	T _{Stg}		-65 to +175	-0			
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	2.0	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased (Only for TO-220)	0.50				
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torgue	minimum			6 (5)	kgf ⋅ cm			
Mounting torque	maximum			12 (10)	(lbf ⋅ in)			
Marking device			Case style D ² PAK	MBRE	31035			
			Case signe D-FAIX	MBRE	31045			

Revision: 17-Nov-16 Document Number: 94302 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



VS-MBRB1035PbF, VS-MBRB1045PbF

Vishay Semiconductors

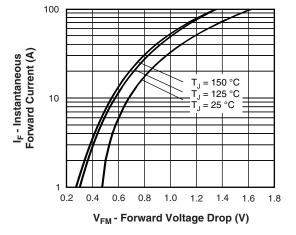


Fig. 1 - Maximum Forward Voltage Drop Characteristics

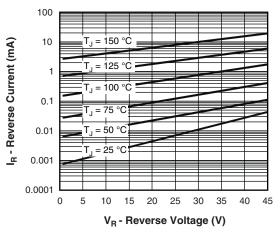


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

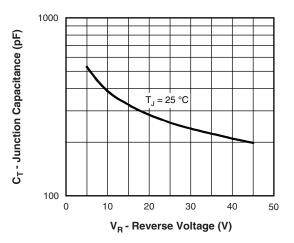


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

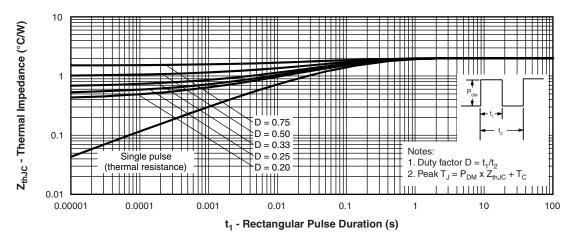


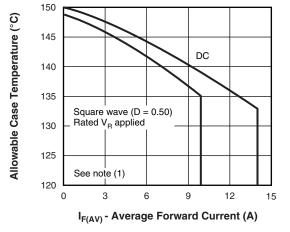
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

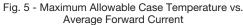
Revision: 17-Nov-16 3 Document Number: 94302 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

www.vishay.com

VS-MBRB1035PbF, VS-MBRB1045PbF

Vishay Semiconductors





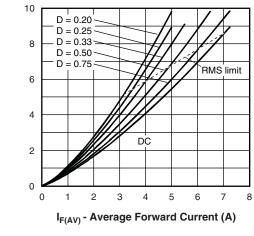
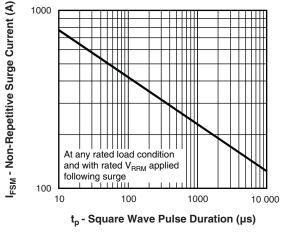


Fig. 6 - Forward Power Loss Characteristics



Average Power Loss (W)

Fig. 7 - Maximum Non-Repetitive Surge Current

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = rated V_R



VS-MBRB1035PbF, VS-MBRB1045PbF

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code	VS-	MBR	В	10	45	TRL	PbF	
		2	3	4	5	6	7	
	 Vishay Semiconductors product Essential part number B = surface mount Current rating (10 = 10 A) Voltage ratings S - Voltage ratings 35 = 35 V 45 = 45 V 							
	• TRL = tape and reel (left oriented)							
	 TRR = tape and reel (right oriented) PbF = lead (Pb)-free 							

LINKS TO RELATED DOCUMENTS								
Dimensions <u>www.vishay.com/doc?95046</u>								
Part marking information	www.vishay.com/doc?95054							
Packaging information	www.vishay.com/doc?95032							
SPICE model	www.vishay.com/doc?95293							

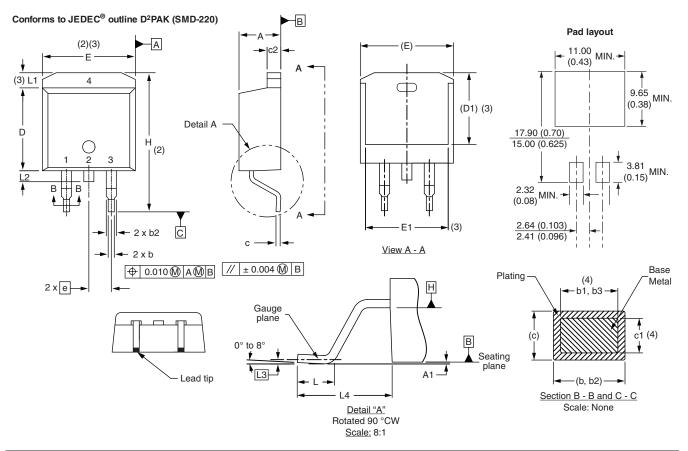
Outline Dimensions



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	ETERS	INCHES		NOTES	NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

1

Document Number: 95046

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.